

Process Change Notice

Parts Affected:

Small signal discrete semiconductors, wafers, and die in chip form.

Extent of Change:

Reduction in the standard die thickness of discrete, small signal wafers from 9.0 mils (230 μ m) \pm 0.6 mils (15 μ m), to 7.1 mils (180 μ m) \pm 0.8 mils (20 μ m).

Reason for Change:

To accommodate assemblies of surface mount, epoxy molded packages, with very low package height (<1.0mm).

Effect of Change:

This change does not affect the electrical characteristics of any device.

Effective Date of Change:

Existing inventory will be shipped until depleted.

Sample Availability:

Please contact Salesperson or Manufacturer's Representative.

Chip Process Part Numbers Affected

Standard Wafer Process Number
9.0 mils thickness (230µm)

CPD48
CPD76
CPD78
CPD80
CPD83
CPD88
CPD91
CPD92
CPD96
CP188
CP191
CP192
CP305
CP307
CP309
CP310
CP314
CP315
CP316
CP317
CP318
CP324
CP355
CP392
CP588
CP591
CP592
CP705
CP709
CP710
CP716
CP720
CP734
CP755
CP767
CP792

New Wafer Process Number
7.1 mils thickness (180µm)

CPD48V
CPD76V
CPD78V
CPD80V
CPD83V
CPD88V
CPD91V
CPD92V
CPD96V
CP188V
CP191V
CP192V
CP305V
CP307V
CP309V
CP310V
CP314V
CP315V
CP316V
CP317V
CP318V
CP324V
CP355V
CP392V
CP588V
CP591V
CP592V
CP705V
CP709V
CP710V
CP716V
CP720V
CP734V
CP755V
CP767V
CP792V